



INTERNATIONAL  
GEMOLOGICAL  
INSTITUTE

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## LABORATORY GROWN DIAMOND REPORT

December 5, 2025

IGI

Report Number

LG754579448

Description

LABORATORY GROWN DIAMOND

Shape and Cutting Style

OVAL BRILLIANT

Measurements

11.98 x 8.03 x 5.03 mm

### GRADING RESULTS

Carat Weight

3.04 CARATS

Color Grade

E

Clarity Grade

VVS 2

### ADDITIONAL GRADING INFORMATION

Polish EXCELLENT

Symmetry EXCELLENT

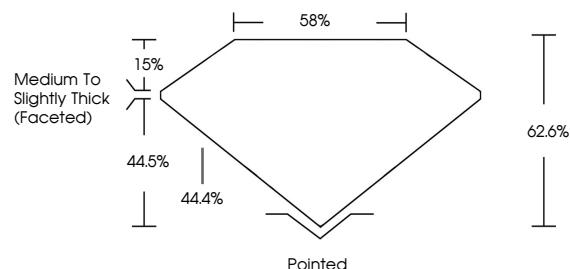
Fluorescence NONE

IGI LG754579448

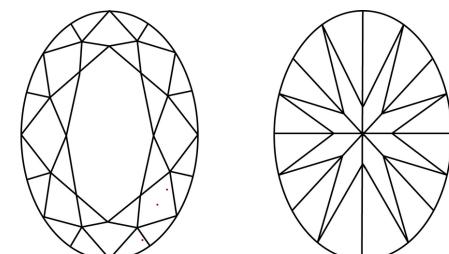
Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.

Type IIa

### PROPORTIONS



### CLARITY CHARACTERISTICS



### KEY TO SYMBOLS

Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.



Sample Image Used

[www.igi.org](http://www.igi.org)

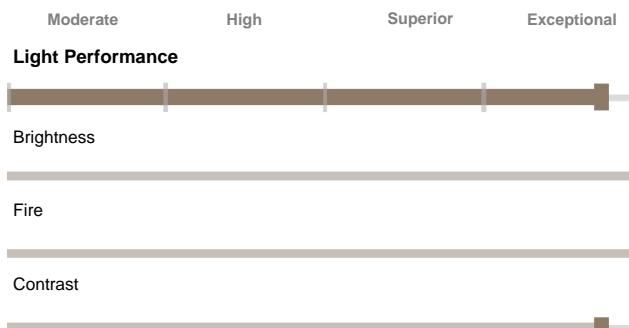
LG754579448  
Report verification at [igi.org](http://igi.org)

### LIGHT PERFORMANCE REPORT

Light Performance Grade: Exceptional



### Structured Light Environment Representation



### COLOR

D E F G H I J Faint Very Light Light

### CLARITY

FL IF VVS<sup>1-2</sup> VS<sup>1-2</sup> SI<sup>1-2</sup> I<sup>1-3</sup>

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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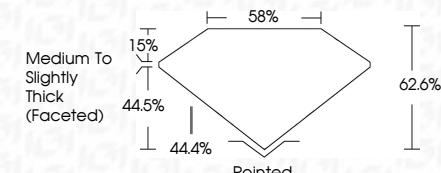
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December 5, 2025

IGI Report Number LG754579448  
Description LABORATORY GROWN DIAMOND  
Shape and Cutting Style OVAL BRILLIANT  
Measurements 11.98 x 8.03 x 5.03 MM

**GRADING RESULTS**  
Carat Weight 3.04 CARATS  
Color Grade E  
Clarity Grade VVS 2



### ADDITIONAL GRADING INFORMATION

Polish EXCELLENT  
Symmetry EXCELLENT  
Fluorescence NONE  
Inscription(s) IGI LG754579448  
Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.  
Type IIa



IGI

December 5, 2025	IGI Report No. LG754579448	3.04 CARATS	E	VVS 2	0.26%	50%	Medium To Slightly Thick (Faceted)	Pointed	EXCELLENT	EXCELLENT	None

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Type IIa